

Supplementary Information

The 4d and 5d Bimetal Doped Tubular Silicon Clusters M_2Si_{12} with M = Nb, Ta, Mo and W: A Bimetallic Configuration Model

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Table S1. the relative energy (kcal/mol) of lower-lying spin state of dimers. M: multiplicity.

Figure S1. The shape of lower-lying isomer of Nb_2Si_{12} , $Nb_2Si_{12}^{2-}$, Ta_2Si_{12} and $Ta_2Si_{12}^{2-}$ clusters. The geometry optimizations were performed using the BP86/aug-cc-pVTZ:M; 6-311+g(d):Si level of theory.

Figure S2. The shape of lower-lying isomer of Mo_2Si_{12} , $Mo_2Si_{12}^{2+}$, W_2Si_{12} and $W_2Si_{12}^{2+}$ clusters. The geometry optimizations were performed using the BP86/aug-cc-pVTZ:M; 6-311+g(d):Si level of theory.

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Figure S3. The shape of lower-lying isomer of $\text{Mo}_2\text{Si}_{12}$, $\text{Mo}_2\text{Si}_{12}^{2+}$, W_2Si_{12} and $\text{W}_2\text{Si}_{12}^{2+}$ clusters. The geometry optimizations were performed using the BP86/aug-cc-pVTZ:M; 6-311+g(d):Si level of theory.

Figure S4. The DOS and pDOS of $\text{Si}_{12}\text{Nb}_2$ cluster.

Figure S5. The DOS and pDOS of $\text{Si}_{12}\text{NbMo}$ cluster.

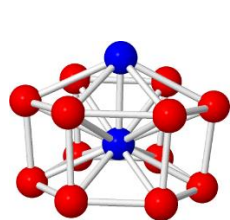
Figure S6. The DOS and pDOS of $\text{Si}_{12}\text{Ta}_2$ cluster.

Figure S7. The DOS and pDOS of Si_{12}W_2 cluster.

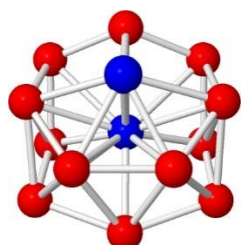
Figure S8. The DOS and pDOS of Si_{12}TaW cluster.

Table S1.

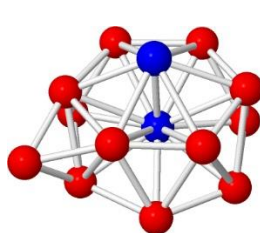
Specie	M=1	M=3	M=5	M=7	Specie	M=2	M=4	M=6	M=8
Mo ₂	0.0	25.0	40.0	55.6	MoNb	0.0	21.9	42.7	73.3
Nb ₂	8.4	0.0	22.0	49.2	WTa	2.2	0.0	22.8	49.4
W ₂	0.0	7.8	19.6	36.4					
Ta ₂	30.7	2.0	0.0	27.1					



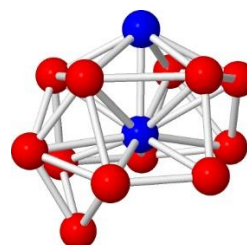
Nb2.A
C_{2v} ¹A₁ 0.00
C_{6v} ³A₁ 9.37



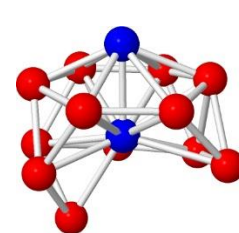
Nb2.B
C_s ¹A' 20.89
C₁ ³A 23.12



Nb2.C
C₁ ¹A 19.72
C₁ ³A 31.78

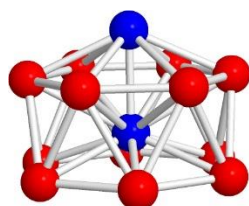


Nb2.D
C₁ ¹A 20.80
C₁ ³A 28.39

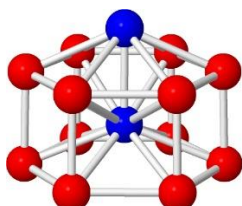


Nb2.E
C₁ ¹A 15.42
C₁ ³A 23.12

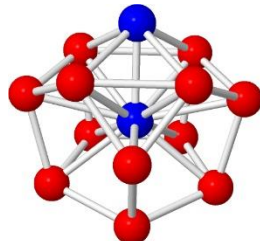
Nb₂Si₁₂



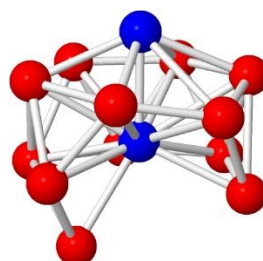
Nb2.da.A
C_{6v} ¹A₁ 0.00



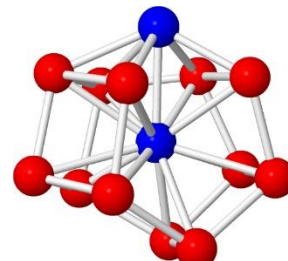
Nb2.da.B
C_{6v} ¹A₁ 26.9



Nb2.da.C
C_s ¹A' 28.04
Si₁₂Nb₂²⁻

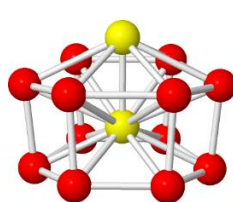


Nb2.da.D
C₁ ¹A 28.51

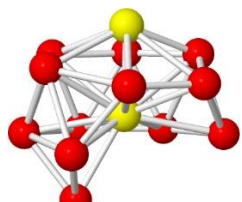


Nb2.da.E
C₁ ¹A 32.95

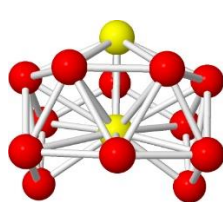
Si₁₂Nb₂²⁻



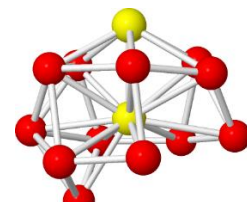
Ta2.A
C_{2v} ¹A₁ 0.00
C₆ ³A 10.69



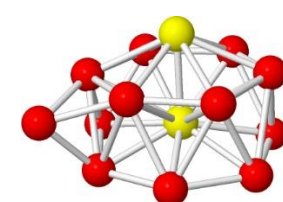
Ta2.B
C₁ ¹A 14.59
C₁ ³A 21.92



Ta2.C
C_s ¹A' 18.40
C₁ ³A 21.92



Ta2.D
C₁ ¹A 18.51
C₁ ³A 19.55



Ta2.E
C₁ ¹A 20.75
C₁ ³A 33.12

Ta₂Si₁₂

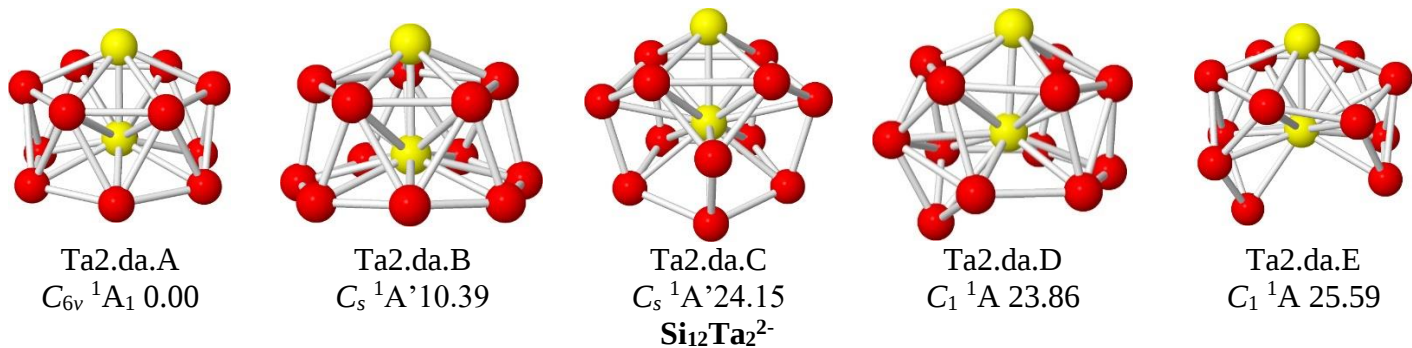
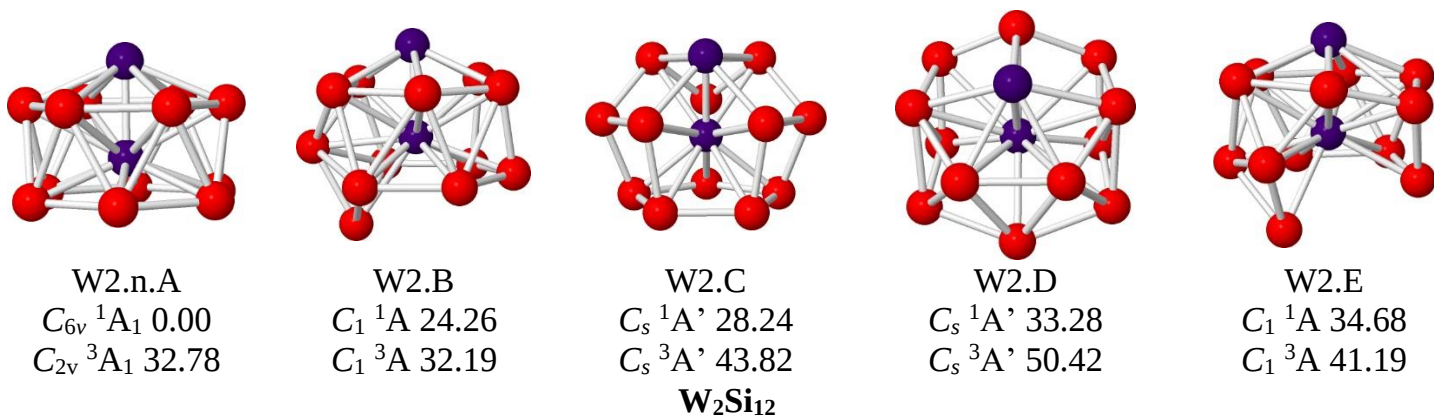
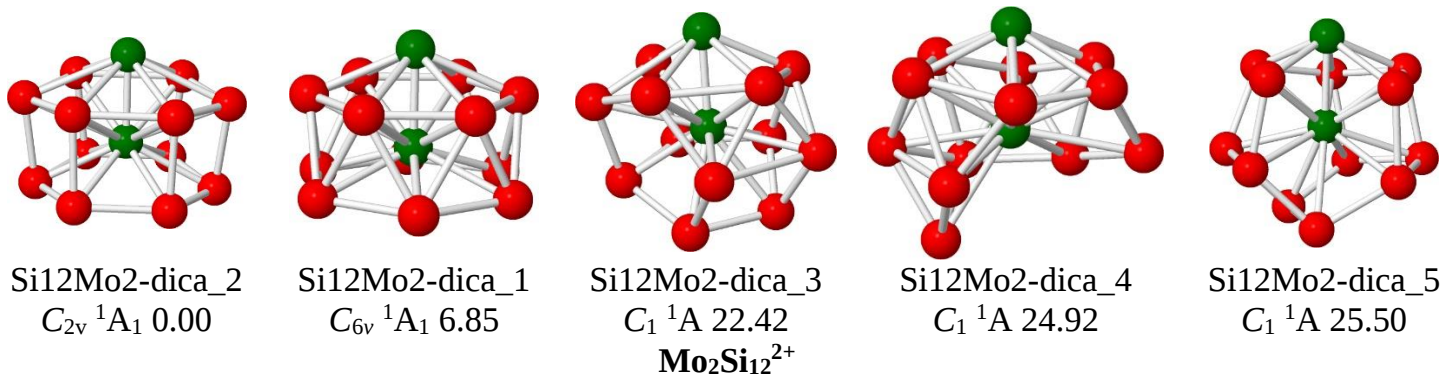
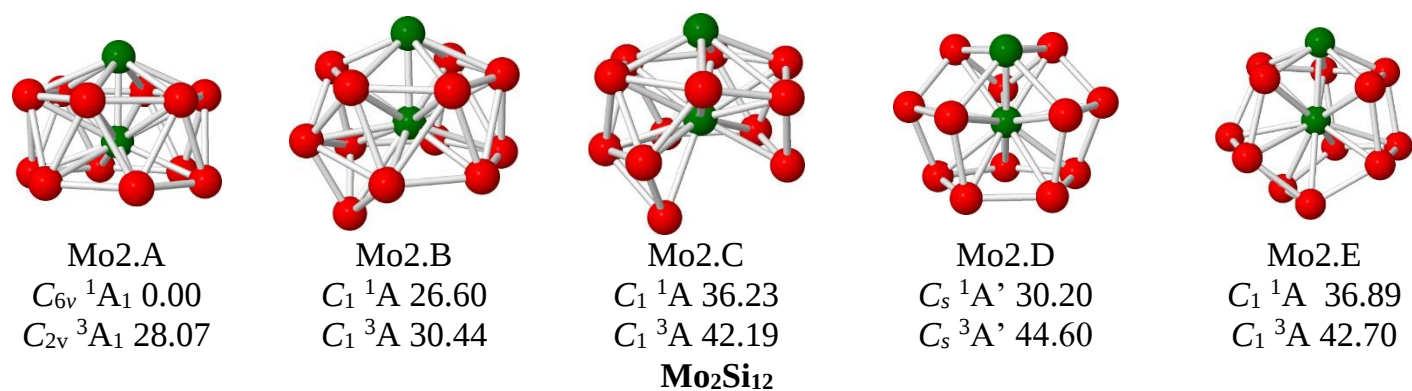


Figure S1.



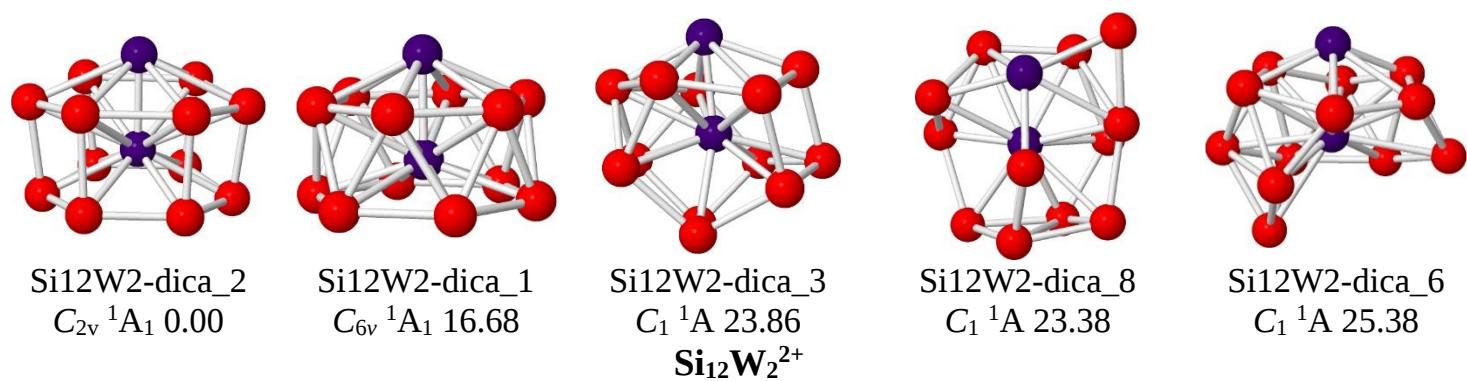
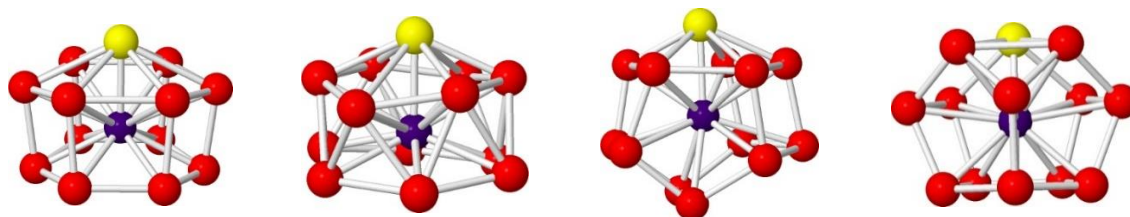
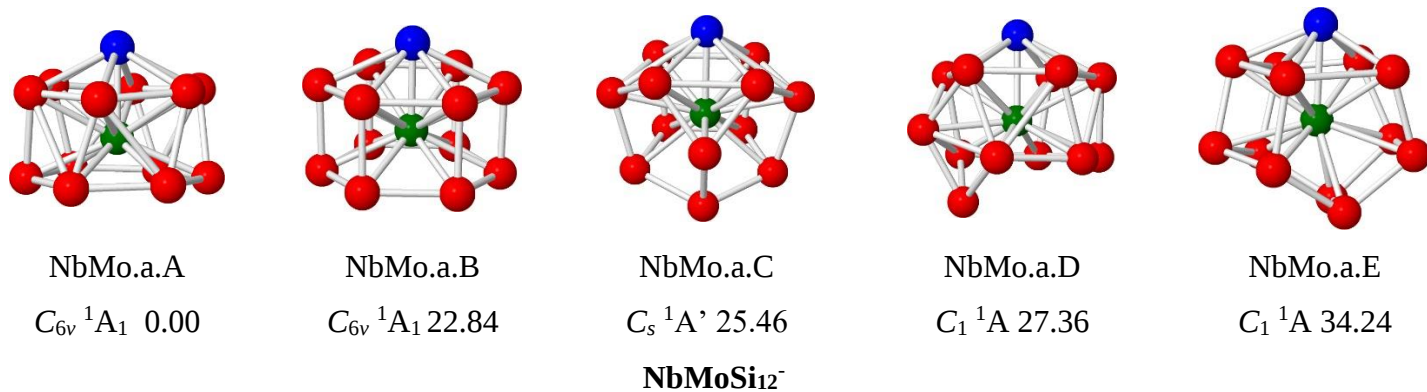
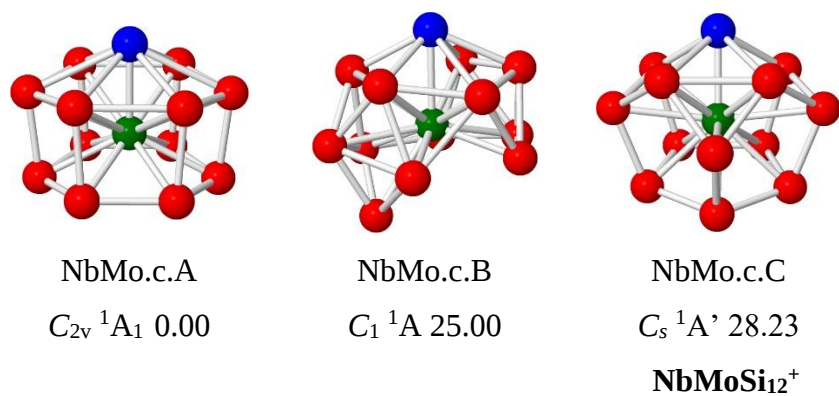


Figure S2



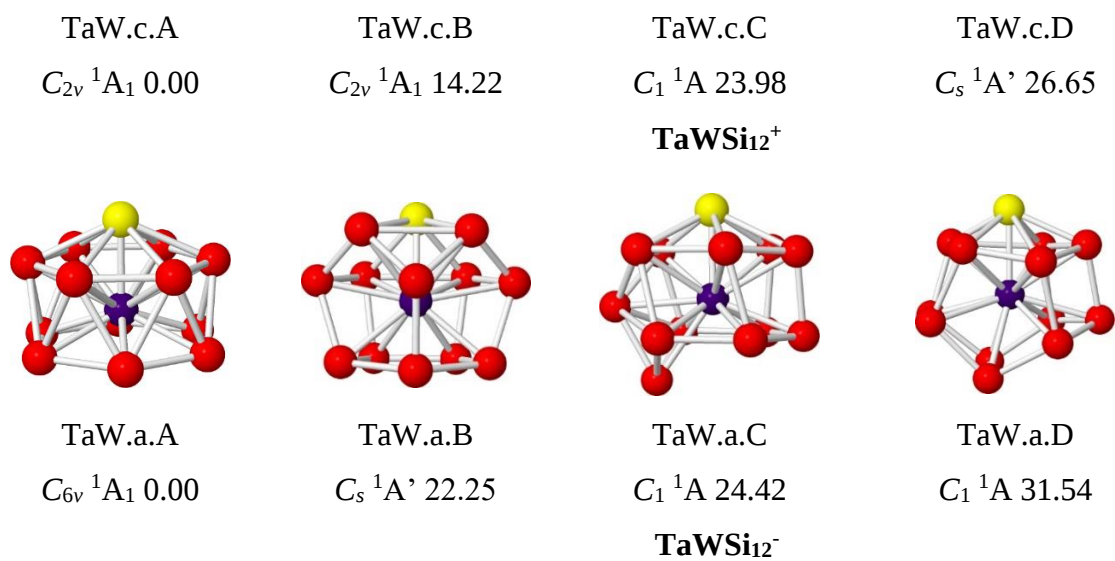


Figure S3

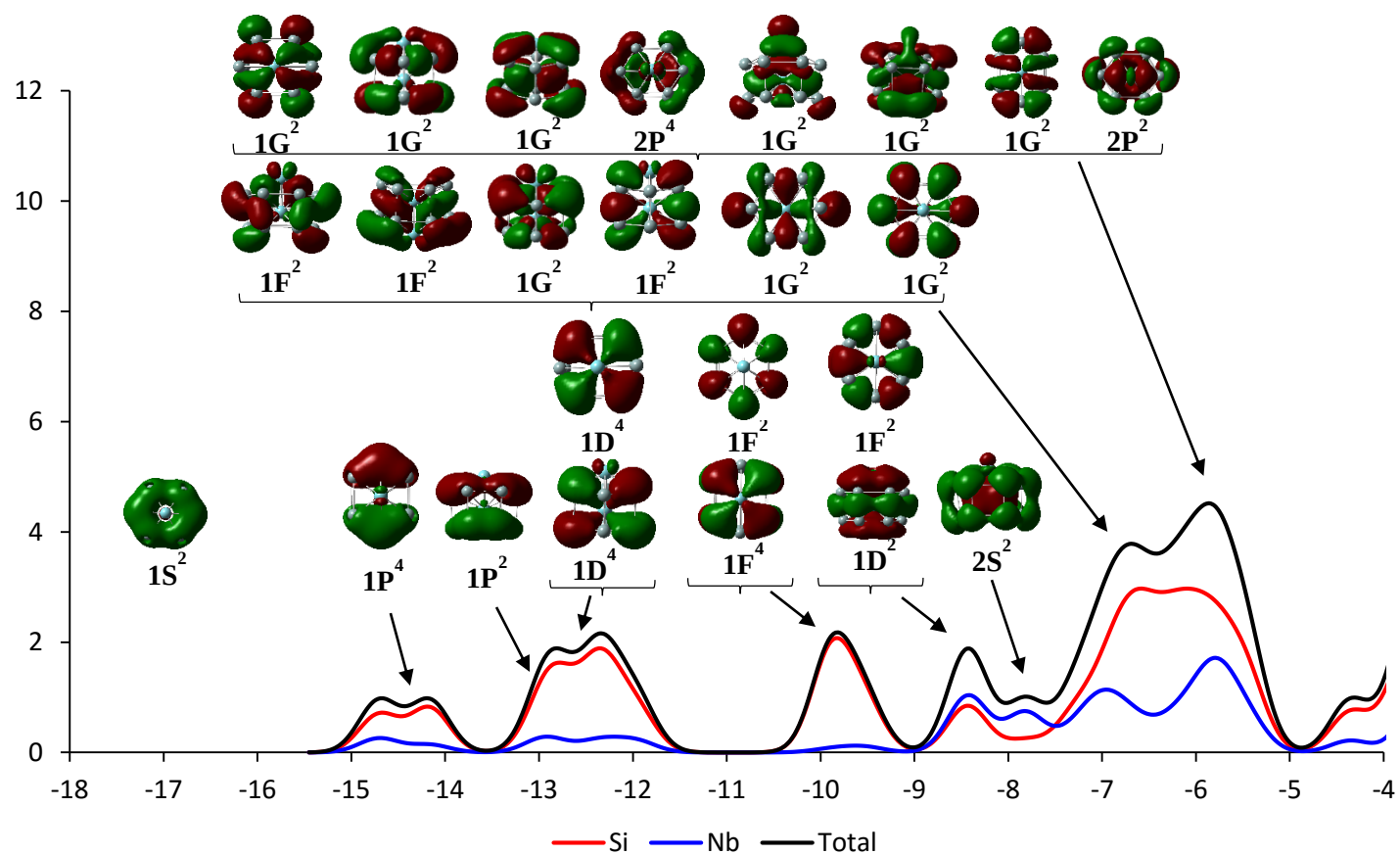


Figure S4.

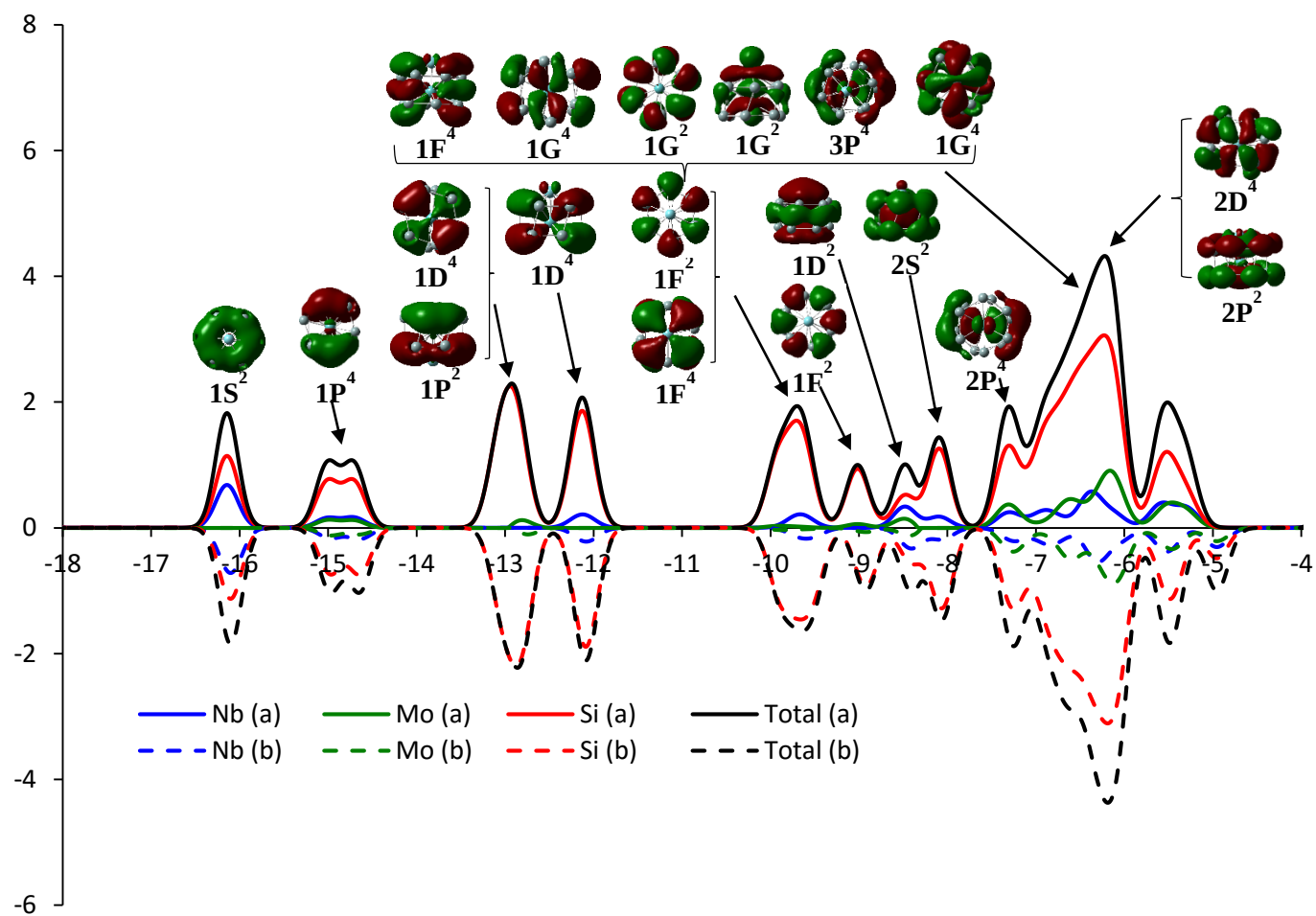


Figure S5.

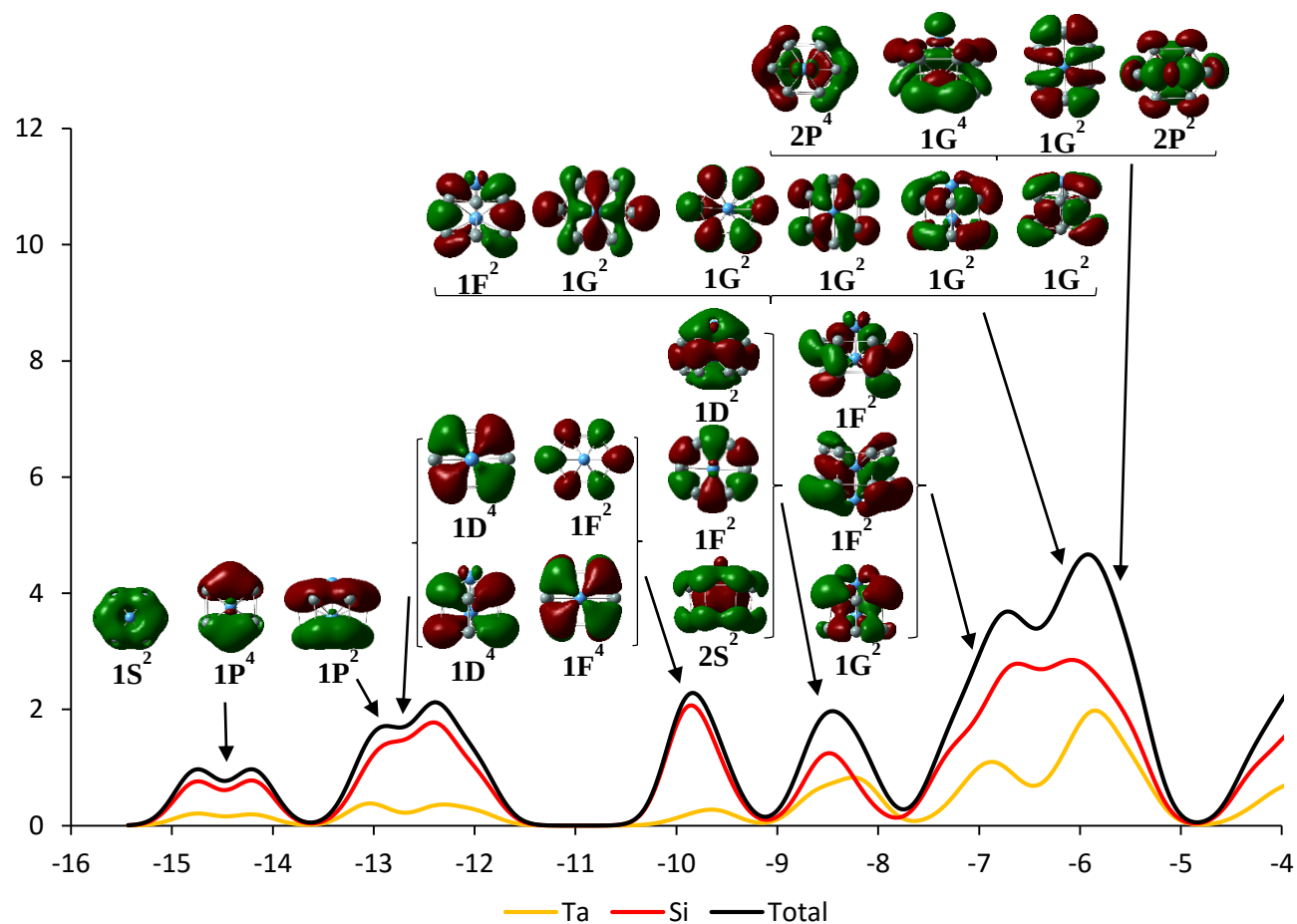


Figure S6.

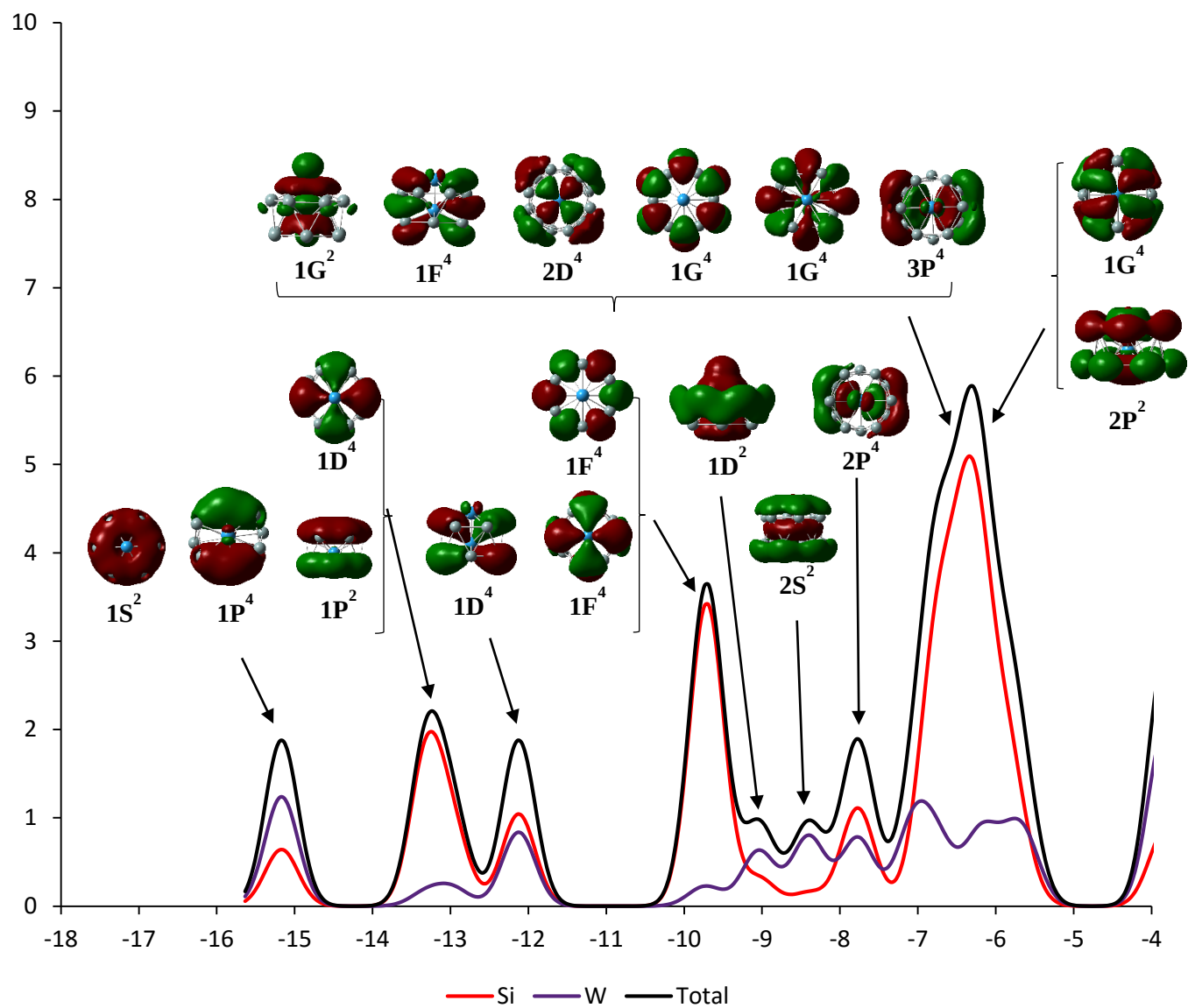


Figure S7.

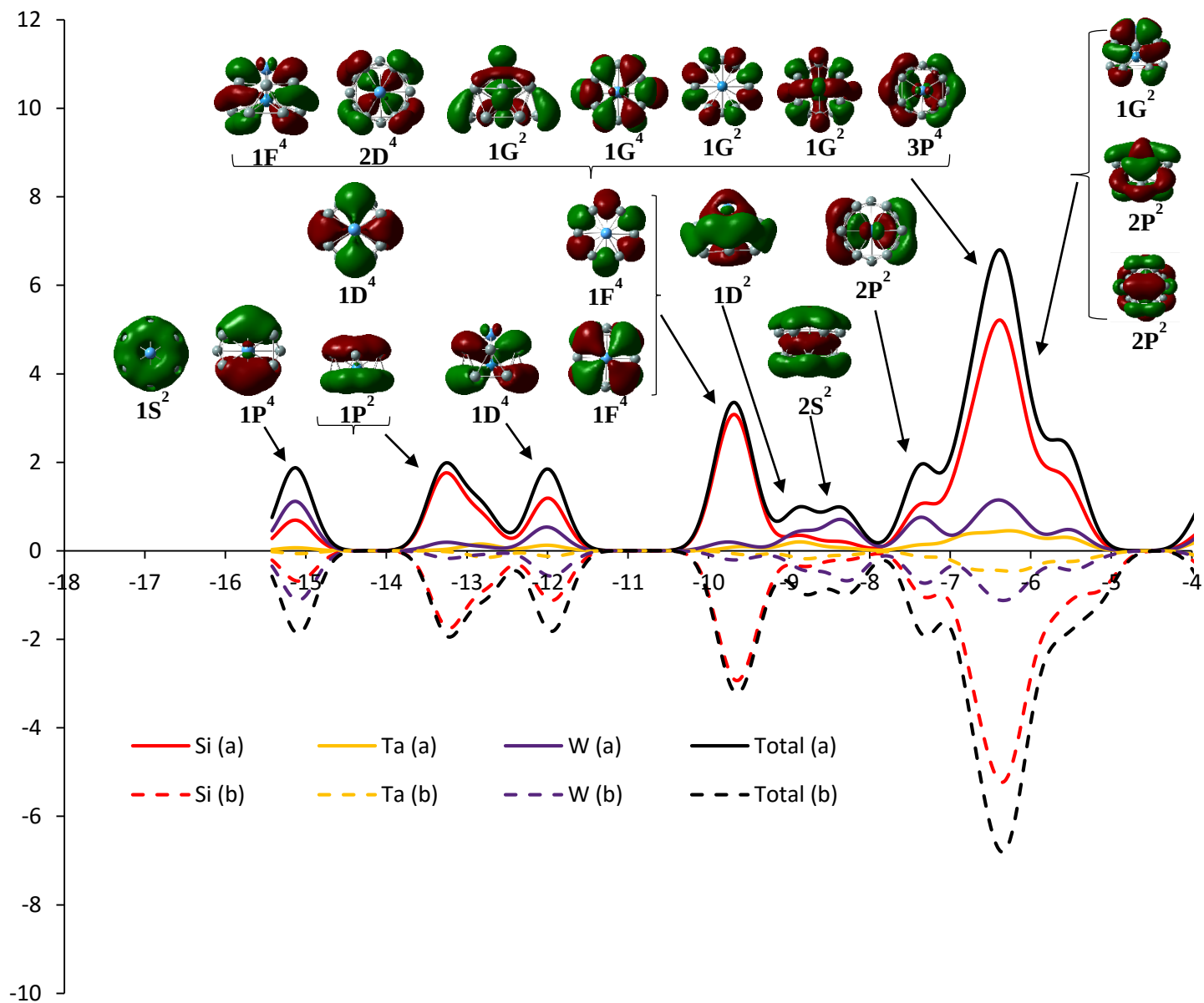


Figure S8.